





Device Number: DPT-958-093 REV: 1.0  
MODEL NO: PT958-8C ECN: \_\_\_\_\_ Page: 2/7

### ©Notes :

- 1.All dimensions are in millimeter.
- 2.General tolerance :  $\pm 0.2\text{mm}$
- 3.Lead spacing are measured where the lead emerges from the package.
- 4.Above specification may be changed without notice. EVERLIGHT will reserve authority on material change for above specification.
- 5.These specification sheets include materials protected under copyright of EVERLIGHT corporation. Please don't reproduce or cause anyone to reproduce them without EVERLIGHT's consent.
- 6.When using this product , please observe the absolute maximum ratings and the instructions for use outlined in these specification sheets. EVERLIGHT assumes no responsibility for any damage resulting from use of the product which does not comply with the absolute maximum ratings and the instructions included in these specification sheets.

### Description

The **PT958-6C** is a high speed and high sensitivity single photo transistor; molded in a clear plastic package with spherical side view lens.

The device is spectrally matched with IR emitters.

### Features

- Wide angle of half sensitivity  $\theta = \pm 11^\circ$
- High sensitivity
- Fast response time

### Applications

- VCR
- Floppy Disk Drive
- Automatic stroboscope
- Cassette type recorder
- Optoelectronic Switch
- Photo interrupter

**Absolute Maximum Ratings**

(Ta=25°C)

Item	Symbol	Rating	Unit
Collector Power Dissipation	Pc	75	mW
Collector-Emitter Voltage	V <sub>CEO</sub>	30	V
Emitter-Collector Voltage	V <sub>ECO</sub>	5	V
Collector Current	Ic	20	mA
Operating Temperature	Topr	-25~+85	°C
Storage Temperature	Tstg	-40~+85	°C
Soldering Temperature (1/16 inch from body for 5 seconds)	Tsol	260	°C

**Electro-Optical Characteristics**

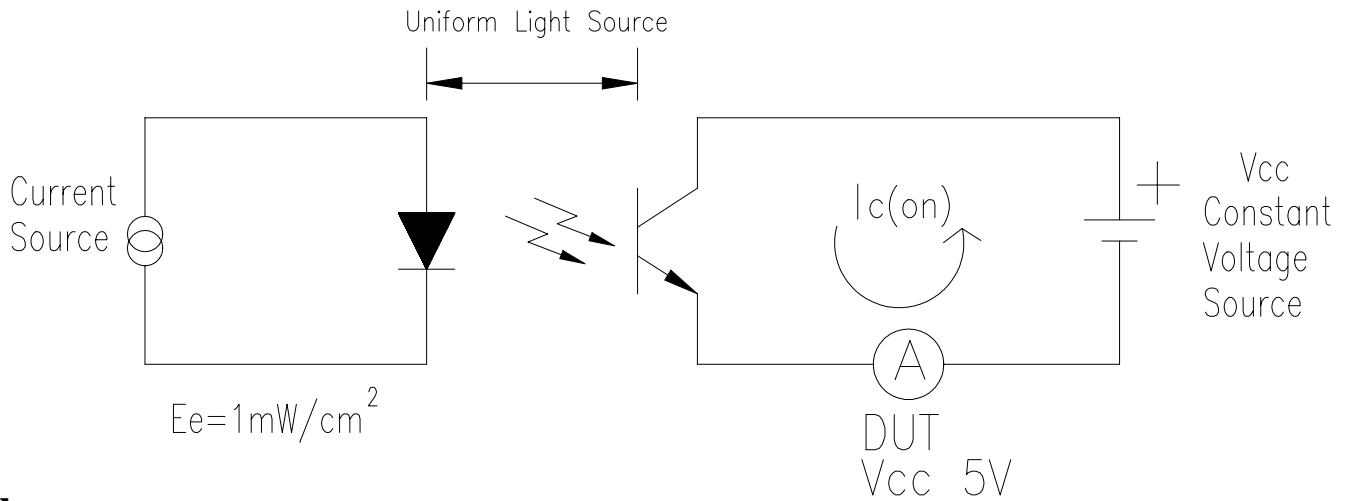
(Ta=25°C)

Parameter	Symbol	Min	Typ	Max	Unit	Condition	
Collector Dark Current	I <sub>CEO</sub>	-	-	100	nA	V <sub>CE</sub> =20V, Ee=0mW/cm <sup>2</sup>	
C-E Saturation Voltage	V <sub>CE(Sat)</sub>	-	-	0.4	V	Ic=0.5mA, Ee=10mW/cm <sup>2</sup>	
Collector Current	I <sub>c(on)</sub>	0.52	-	3.48	mA	V <sub>CE</sub> =5V, Ee=1mW/cm <sup>2</sup>	
Wavelength of Peak Sensitivity	λ <sub>p</sub>	-	860	-	nm	---	
Range of Spectral Bandwidth	λ <sub>0.5</sub>		400...1200	-	nm	---	
Response Time	Rise Time	t <sub>r</sub>	-	15	-	μ Sec	V <sub>CE</sub> =5V Ic=1mA R <sub>L</sub> =1000Ω
	Fall Time	t <sub>f</sub>	-	15	-	μ Sec	
Half sensitivity angle	2θ 1/2	-	± 11	-	Deg	---	



**Test Method**

The collector current testing method for PTR:



**Ranks**

Color Code	Parameter	Symbol	Min	Typ	Max	Unit	Test Condition
Red	7-3	Ic(on)	0.52	-	1.22	mA	Ee=1mw/cm <sup>2</sup> Vcc=5V
Blue	7-2	Ic(on)	0.87	-	1.74	mA	Ee=1mw/cm <sup>2</sup> Vcc=5V
Yellow	7-1	Ic(on)	1.22	-	2.26	mA	Ee=1mw/cm <sup>2</sup> Vcc=5V
Silver	6-2	Ic(on)	1.56	-	3.04	mA	Ee=1mw/cm <sup>2</sup> Vcc=5V
Green	6-1	Ic(on)	1.74	-	3.48	mA	Ee=1mw/cm <sup>2</sup> Vcc=5V

**Supplement**

1.Parts

(1) Chip

Type	Material	Peak Wavelength
PT	Silicon	860nm

(2) Material

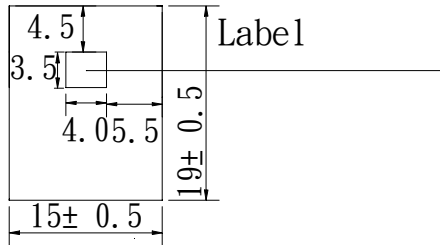
Type	Lead frame	Wire	Package
Material	SPCC	Gold	Epoxy



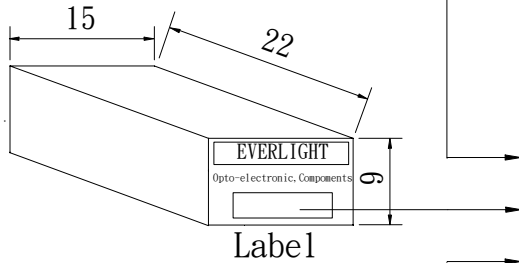


### Packing Specifications

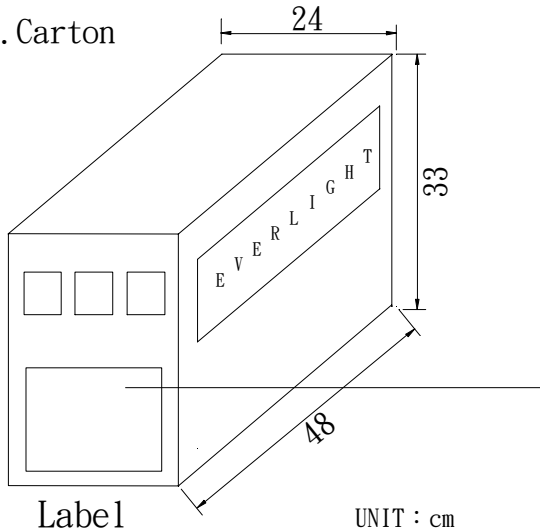
1. Bag



2. Box



3. Carton



**CPN:** Customer's product number

**P/N:** Product number

**QTY:** Packing quantity

**CAT:** Ranks

**HUE:** Reference

**REF:** Reference

**LOT NO:** Lot number

**MADE IN TAIWAN:** Production place

### Packing Quantity Specification

1.1000Pcs/1Bag

2.10Bags/1Box

3.10Boxes/1Carton